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DISPLAY****Publication Classification**

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(57) **ABSTRACT**

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An organic light emitting diode (OLED) display including a substrate main body; a driving circuit on the substrate main body; an organic light emitting element on the driving circuit; and a front substrate covering the organic light emitting element and coupled to the substrate main body, wherein the driving circuit includes a wire, the wire including a planar portion parallel to a surface of the substrate main body, and a connection portion connected to the planar portion and extending in a direction orthogonal to the substrate main body.

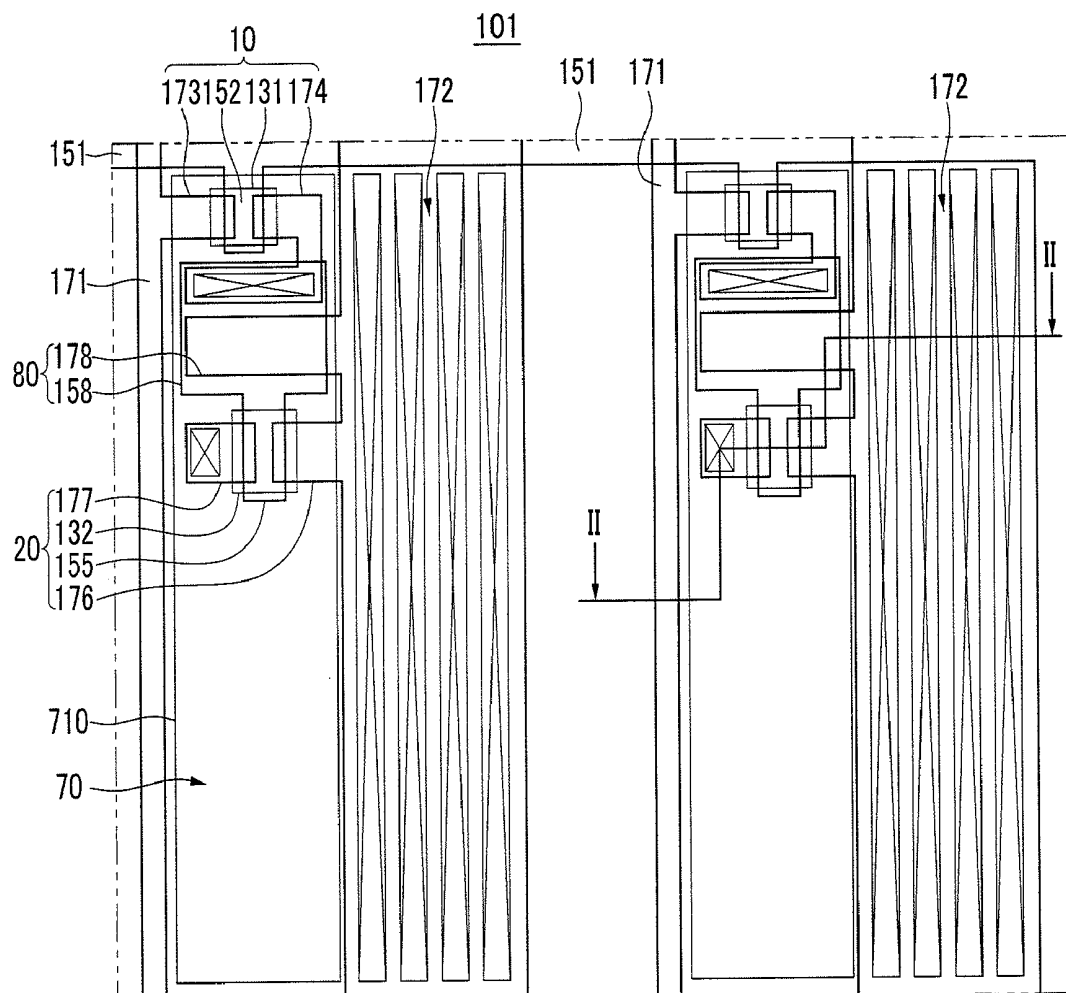
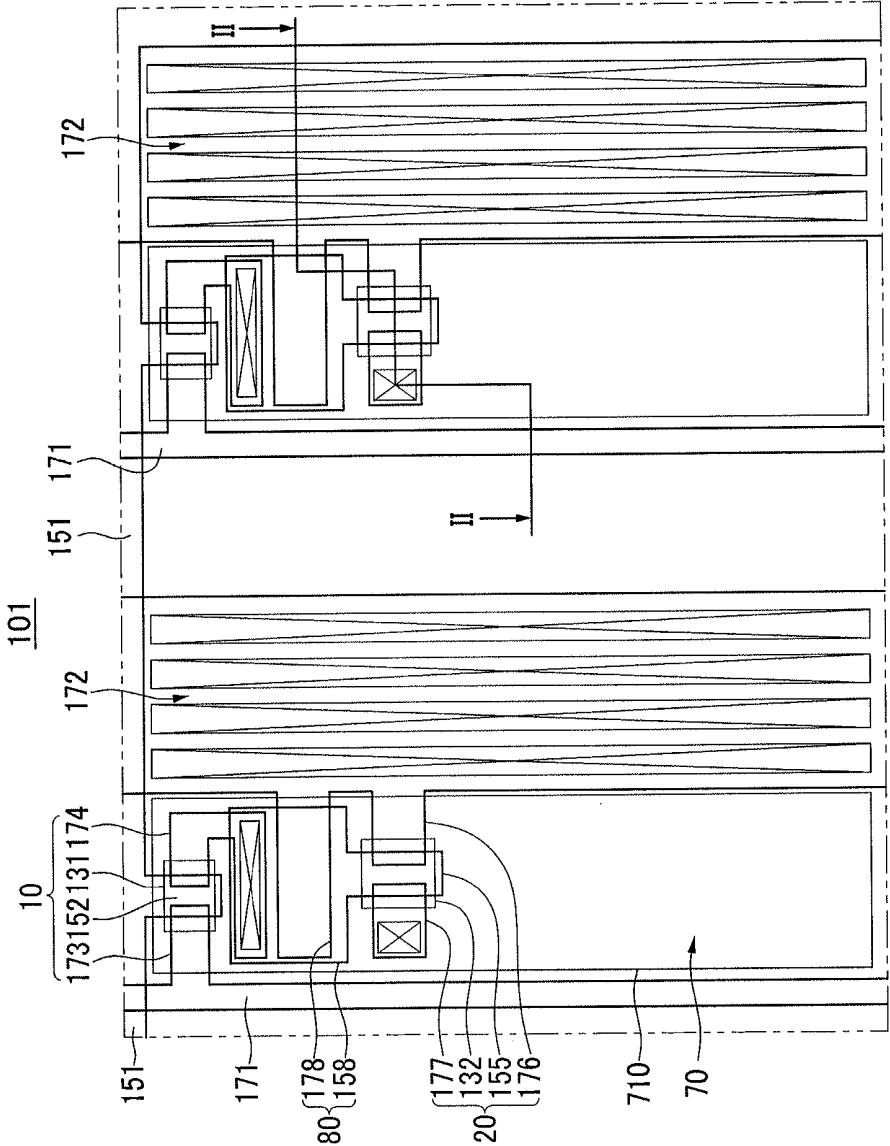


FIG.1



ORGANIC LIGHT EMITTING DIODE DISPLAY

BACKGROUND

[0001] 1. Field

[0002] Embodiments relate to an organic light emitting diode (OLED) display.

[0003] 2. Description of the Related Art

[0004] An organic light emitting diode (OLED) display is a self emissive display device that displays images with organic light emitting diodes. The organic light emitting diode emits light by way of energy generated when excitons, being combinations of electrons and holes, within an organic emission layer fall from an excited state to a ground state. Thus, the OLED display displays an image using the light.

[0005] The organic light emitting diode (OLED) display may include a switching thin film transistor, a driving thin film transistor, and a capacitor. A common drain voltage V_{dd} may be applied to a driving source electrode of the driving thin film transistor. The driving drain electrode may be applied with a common source voltage V_{ss} . A current flowing in the organic light emitting element may be controlled by the magnitude of data voltage V_{data} applied to the driving gate electrode through the switching thin film transistor.

[0006] In order to emit uniform light from the organic light emitting diode (OLED) display, the common drain voltage V_{dd} should be applied with uniform voltage. However, as the common drain power line (hereinafter, "a common power line") applying the common drain voltage (V_{dd} , hereinafter, "a common voltage") is elongated, the line resistance may be increased, and thus a voltage drop (IR drop) may be generated.

[0007] Therefore, the common voltage may be changed according to a position of the common power line such that the same current may not flow to all driving thin film transistors even though one data voltage is applied. The organic light emitting element in which the light emitting degree is determined according to the current may not emit light of a uniform luminance.

[0008] Accordingly, consideration of the voltage drop may be important as a size of the organic light emitting diode (OLED) display is increased.

[0009] The above information disclosed in this Background section is only for enhancement of understanding of the background of the described technology and therefore it may contain information that does not form the prior art that is already known in this country to a person of ordinary skill in the art.

SUMMARY

[0010] Embodiments are directed to an organic light emitting diode (OLED) display, which represents advances over the related art.

[0011] It is a feature of an embodiment to provide an OLED display having a wire that is disposed on a substrate main body and exhibits low resistance.

[0012] The embodiments may be realized by providing an organic light emitting diode (OLED) display including a substrate main body; a driving circuit on the substrate main body; an organic light emitting element on the driving circuit; and a front substrate covering the organic light emitting element and coupled to the substrate main body, wherein the driving circuit includes a wire, the wire including a planar portion

parallel to a surface of the substrate main body, and a connection portion connected to the planar portion and extending in a direction orthogonal to the substrate main body.

[0013] The driving circuit may include a switching thin film transistor connected to a gate line and a data line, the gate line and data line intersecting each other and being insulated from each other, a storage capacitor connected to the switching thin film transistor and a common power line, the common power line being insulated from the gate line and the data line, and a driving thin film transistor connected to the switching thin film transistor, the storage capacitor, the common power line, and the organic light emitting element, and the wire may be a common power line.

[0014] The organic light emitting diode (OLED) display may further include an interlayer insulation layer and a gate insulator layer on the substrate main body, wherein the storage capacitor includes capacitor plates, the capacitor plates being insulated from one another by the interlayer insulation layer, the driving thin film transistor includes a gate electrode, the gate electrode being insulated by the gate insulator layer in a thickness direction thereof, and the connection portion is disposed on an inner side surface of a hole in the interlayer insulation layer and the gate insulator layer.

[0015] The interlayer insulation layer and the gate insulator layer may include a plurality of holes therein, and the common power line may include a plurality of connection portions, the plurality of connection portions being respectively disposed on inner side surfaces of the plurality of holes.

[0016] The planar portion may include a first planar portion on the interlayer insulation layer, and a second planar portion on an inner surface of the substrate main body in the hole, the second planar portion being connected to the first planar portion by the connection portion.

[0017] The organic light emitting diode (OLED) display may further include an interlayer insulation layer on the substrate main body, wherein the storage capacitor includes capacitor plates, the capacitor plates being insulated from one another by the interlayer insulation layer, the interlayer insulation layer includes a first groove therein, and the connection portion is disposed on an inner side surface of the at least one first groove in the interlayer insulation layer.

[0018] The organic light emitting diode (OLED) display may further include a gate insulation layer on the substrate main body, wherein the driving thin film transistor includes a gate electrode, the gate electrode being insulated by the gate insulator layer in a thickness direction thereof, and the interlayer insulation layer includes at least one first corresponding portion, the at least one first corresponding portion forming the first groove and being formed on an inner surface of a second groove in the gate insulator layer.

[0019] The organic light emitting diode (OLED) display may further include a buffer layer on an inner surface of the substrate main body, wherein the gate insulation layer includes a second corresponding portion, the second corresponding portion forming the second groove and being formed on an inner surface of a third groove in the buffer layer, and the inner surface of the substrate main body.

[0020] The interlayer insulation layer may include a plurality of the first grooves therein, the gate insulator layer may include a plurality of the second grooves therein, the buffer layer may include a plurality of the third grooves therein, and the common power line may include a plurality of connection portions, the plurality of connection portions being respec-

tively disposed on inner surfaces of the first grooves and being connected to each other through the planar portion.

[0021] The planar portion may include a first planar portion on the interlayer insulation layer, and a second planar portion on an inner bottom surface of the first groove, the second planar portion being connected to the first planar portion by the connection portion.

[0022] The embodiments may also be realized by providing an organic light emitting diode (OLED) display including a lower structure including a first portion that is substantially flat and a second portion that has a different height than the first portion; a driving circuit on the lower structure, the driving circuit having at least one wire; an organic light emitting element on the driving circuit; and an upper structure on the organic light emitting element, wherein the at least one wire is continuously disposed on the first and second portions and including at least one step.

[0023] The driving circuit may include a switching thin film transistor connected to a gate line and a data line, the gate line and data line intersecting each other and being insulated from each other, a storage capacitor connected to the switching thin film transistor and a common power line, the common power line being insulated from the gate line and the data line, and a driving thin film transistor connected to the switching thin film transistor, the storage capacitor, the common power line, and the organic light emitting element, and the wire may be a common power line.

[0024] The first portion may correspond to the first insulating material, and the second portion may correspond to the second insulating material.

[0025] The lower structure may include a first insulating material; and a second insulating material on the first insulating material. The lower structure may also be a unitary structure.

[0026] The first insulating material may include a glass substrate and may be a unitary structure.

[0027] The second insulating material may be a unitary structure.

[0028] The first portion may correspond to the first insulating material, and the second portion may correspond to the second insulating material.

[0029] The lower structure may be a unitary structure.

BRIEF DESCRIPTION OF THE DRAWINGS

[0030] The above and other features and advantages will become more apparent to those of ordinary skill in the art by describing in detail exemplary embodiments with reference to the attached drawings, in which:

[0031] FIG. 1 illustrates a layout view of a pixel circuit of an organic light emitting diode (OLED) display according to an embodiment;

[0032] FIG. 2 illustrates a cross-sectional view taken along line II-II of FIG. 1; and

[0033] FIG. 3 illustrates a cross-sectional view of an organic light emitting diode (OLED) display according to another embodiment.

DETAILED DESCRIPTION

[0034] Korean Patent Application No. 10-2010-0024422 filed on Mar. 18, 2010, and Korean Patent Application No. 10-2011-0023871 filed on Mar. 17, 2011, in the Korean Intel-

lectual Property Office, and entitled: "Organic Light Emitting Diode Display," are incorporated by reference herein in their entirety.

[0035] Example embodiments will now be described more fully hereinafter with reference to the accompanying drawings; however, they may be embodied in different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are provided so that this disclosure will be thorough and complete, and will fully convey the scope of the invention to those skilled in the art.

[0036] In the drawing figures, the dimensions of layers and regions may be exaggerated for clarity of illustration. It will also be understood that when a layer or element is referred to as being "on" another layer or substrate, it can be directly on the other layer or substrate, or intervening layers may also be present. In addition, it will also be understood that when a layer is referred to as being "between" two layers, it can be the only layer between the two layers, or one or more intervening layers may also be present. Like reference numerals refer to like elements throughout.

[0037] FIG. 1 illustrates a layout view of a pixel circuit of an organic light emitting diode (OLED) display according to an embodiment. FIG. 2 illustrates a cross-sectional view taken along the line II-II of FIG. 1. Referring to FIG. 1 and FIG. 2, an organic light emitting diode (OLED) display 101 according to an embodiment may include a substrate main body 111, a driving circuit DC, an organic light emitting element 70, and a front substrate 200.

[0038] The substrate main body 111 may be formed as an insulating substrate made of, e.g., glass, quartz, ceramic, plastic, or the like, or as a flexible substrate made of, e.g., plastic or the like. In an implementation, the substrate main body 111 may be formed as a metallic substrate made of, e.g., stainless steel or the like.

[0039] The driving circuit DC and the organic light emitting element 70 may be formed on the substrate main body 111. The driving circuit DC may include thin film transistors 10 and 20 and may drive the organic light emitting element 70. The organic light emitting element 70 may emit light according to a driving signal transmitted from the driving circuit DC.

[0040] The front substrate 200 may be coupled to the substrate main body 111 on the organic light emitting element 70, thereby protecting the driving circuit DC and the organic light emitting element 70.

[0041] An inner structure of the organic light emitting diode (OLED) display 101 will now be described. FIG. 1 and FIG. 2 illustrate an active matrix (active matrix, AM) organic light emitting diode (OLED) display 101 having a 2Tr-1Cap structure in which one pixel includes two thin film transistors (TFT) 10 and 20 and one capacitor 80.

[0042] However, the embodiments are not limited thereto. Accordingly, the organic light emitting diode display 101 may be provided with three or more thin film transistors and two or more storage capacitors in one pixel and may be configured to have various structures with additional wires. Herein, the pixel represents a base unit for displaying an image and is disposed in each pixel area. The organic light emitting diode display 101 displays an image through a plurality of pixels.

[0043] As illustrated in FIG. 1 and FIG. 2, a switching thin film transistor 10, a driving thin film transistor 20, a storage capacitor 80, and an organic light emitting diode (OLED) 70 may be formed on the substrate main body 111 for each pixel.

[0044] Herein, a configuration including the switching thin film transistor **10**, the driving thin film transistor **20**, and the storage capacitor **80** is referred to as a driving circuit DC. In addition, a buffer layer **120** may be further formed between the substrate main body **111** and the driving circuit DC and the organic light emitting element **70** (referring to FIG. 3). The buffer layer **120** may have a single-layer structure of, e.g., silicon nitride (SiN_x), or a dual-layer structure of, e.g., silicon nitride (SiN_x) and silicon oxide (SiO_2). The buffer layer **120** may prevent penetration of harmful and/or unnecessary elements, e.g. impurity atoms or moisture, and may planarize the surface. However, the buffer layer **120** may not be required, and may be omitted according to the type and process conditions of the substrate main body **111** (referring to FIG. 2).

[0045] In addition, at least one wire is disposed on the substrate main body **111**. That is, the substrate main body **111** may further include a gate line **151** disposed in one direction, a data line **171** insulated from and crossing the gate line **151**, and a common power supply line **172** (referring to FIG. 1). The common power line may intersect the data line (not shown). Herein, one pixel may be defined by boundaries of the gate line **151**, the data line **171**, and the common power supply line **172**, but is not limited thereto.

[0046] The organic light emitting diode **70** may include a first electrode **710**, an organic emission layer **720** on the first electrode **710**, and a second electrode **730** on the organic emission layer **720**. Holes and electrons may be injected into the organic emission layer **720** from each of the first electrode **710** and the second electrode **730**. When excitons generated by combination of the injected holes and electrons in the organic emission layer return from an excited state to a ground state, light is emitted.

[0047] The storage capacitor **80** may include a pair of capacitor plates **158** and **178** with an interlayer insulating layer **160** interposed therebetween. Herein, the interlayer insulating layer **160** may function as a dielectric. Storage capacity may be determined by electric charges stored in the storage capacitor **80** and a voltage difference between the capacitor plates **158** and **178**.

[0048] The switching thin film transistor **10** may include a switching semiconductor layer **131**, a switching gate electrode **152**, a switching source electrode **173**, and switching drain electrode **174**. The driving thin film transistor **20** may include a driving semiconductor layer **132**, a driving gate electrode **155**, a driving source electrode **176**, and a driving drain electrode **177**.

[0049] The switching thin film transistor **10** may serve as a switching element that selects a desired pixel to emit light. The switching gate electrode **152** may be connected to the gate line **151**. The switching source electrode **173** may be connected to the data line **171**. The switching drain electrode **174** may be disposed away from the switching source electrode **173** and may be connected to either capacitor plate (**158** in this case).

[0050] The driving thin film transistor **20** may apply driving power to the pixel electrode **710** in order to allow the organic emission layer **720** of the organic light emitting diode **70** to emit light in the selected pixel. The driving gate electrode **155** may be connected to the capacitor plate **158** connected to the switching drain electrode **174**. Each of the driving source electrode **176** and the other capacitor plate **178** may be connected to the common power supply line **172**. The driving

drain electrode **177** may be connected to the pixel electrode **710** of the organic light emitting diode **70** through a contact hole.

[0051] By this structure, the switching thin film transistor **10** may be operated by a gate voltage applied to the gate line **151** to transmit a data voltage applied to the data line **171** to the driving thin film transistor **20**. A voltage corresponding to a difference between a common voltage applied to the driving thin film transistor **20** from the common power supply line **172** and the data voltage transmitted from the switching thin film transistor **10** may be stored in the storage capacitor **80** and a current corresponding to the voltage stored in the storage capacitor **80** may flow to the organic light emitting diode **70** through the driving thin film transistor **20** to allow the organic light emitting diode **70** to emit light.

[0052] However, the structure of the thin film transistors **10** and **20** and the organic light emitting element **70** is not limited to the examples illustrated FIG. 1 and FIG. 2. That is, the structure of the thin film transistors **10** and **20** and organic light emitting element **70** may be modified within the scope in which a person skilled in the art may easily implement the OLED.

[0053] The common power line **172** may be connected to the driving source electrode **176** of the driving thin film transistor **20**, thereby applying the common voltage to the first electrode **710** of the organic light emitting element **70** through the driving thin film transistor **20**. In the present embodiment, the common power line **172** may reduce resistance against the common voltage for uniform current to be supplied to the organic light emitting elements **70**.

[0054] In particular, the common power line **172** may include a planar portion **721** parallel to a surface of the substrate main body **111** and a connection portion **722** connected in a thickness direction (i.e., substantially perpendicular to the surface of the substrate main body **111** or an up and down direction of FIG. 2) of the substrate main body **111** at ends of the planar portion **721**. Also, the planar portion **721** and the connection portion **722** may form a pattern connected according to a length direction of the common power line **172**. That is, when widths of the planar portions **721** are equal to each other, the connection portion **722** may increase a width of the entire line of the common power line **172**.

[0055] A hole H may be integrally formed in the interlayer insulation layer **160** and the gate insulator layer **130** in a thickness direction thereof. The hole H may form a pattern such that the interlayer insulation layer **160** is connected to the gate insulator layer **130** according to a length direction of the common power line **172**. The hole H pattern may be formed during a process of forming a contact hole in the interlayer insulation layer **160** to connect the driving semiconductor layer **132** to the driving source electrode **176** and the driving drain electrode **177** such that an additional process may not be required. The gate insulator layer **130** may be formed on an inner surface of the driving semiconductor layer **132** and the substrate main body **111** such that the driving semiconductor layer **132** and the gate electrode **155** are insulated from each other.

[0056] The planar portion **721** may include a first planar portion **723** on the interlayer insulation layer **160** and a second planar portion **724** on an inner surface of the substrate main body **111** in the hole H. The connection portion **722** may be disposed on an inner surface of the hole H, thereby con-

necting the first and second planar portions 723 and 724 to each other and thus forming an entire line width of the common power line 172.

[0057] That is, the common power line 172 may be formed by adding the line width of the connection portion 722 to the line width of the first and second planar portions 723 and 724. In an implementation, a plurality of holes H may be disposed in the interlayer insulation layer 160 and the gate insulator layer 12 and the connection portion 722 may be respectively formed on inner surfaces of the holes H such that a plurality of connection portions 722 are connected to each other through the first and second planar portions 723 and 724. To form the common power line 172, a number of connection portions 722 may be increased as a number of holes H is increased in a predetermined range. Thus, the line width of the common power line 172 may be increased and resistance of the common voltage may be reduced.

[0058] Although a common power line was taken as an example of a wire in the above descriptions, wires other than the common power line that are disposed on the substrate main body may be formed to be similar to the common power line in order to lower their resistance, if necessary.

[0059] Next, another embodiment will be described in comparison with the previous embodiment. Description of like configurations is omitted and different configurations will be described.

[0060] FIG. 3 illustrates a cross-sectional view of an organic light emitting diode (OLED) display according to another embodiment. The organic light emitting diode (OLED) display 102 of the present embodiment may further include the buffer layer 120 between the substrate main body 111 and the gate insulator layer 130. In this case, the buffer layer 120 may be formed on the substrate main body 111 and a portion corresponding to the connection portion 722 and the second planar portion 724 of a common power line 272 may be patterned.

[0061] The connection portion 722 may be formed on an inner surface of a first groove G1 in the interlayer insulation layer 160. The interlayer insulation layer 160 may include a first corresponding portion R1 forming the first groove G1, and the first corresponding portion R1 may be formed on an inner surface of a second groove G2 formed in the gate insulator layer 130. The gate insulator layer 130 may include a second corresponding portion R2 forming the second groove G2. The second corresponding portion R2 may be formed on an inner surface of the third groove G3 formed in the buffer layer 120 on an inner surface of the substrate main body 111 and on the inner surface of the substrate main body 111.

[0062] In an implementation, a plurality of first groove G1 may be formed in the interlayer insulation layer 160, a plurality of second grooves G2 may be formed in the gate insulator layer 130, and a plurality of third grooves G3 may be formed in the buffer layer 120. Further, the connection portion 722 may be formed on an inner surface of the first groove G1, thereby connecting to the planar portion 721. The planar portion 721 may include the first and second planar portions 723 and 724.

[0063] The first planar portion 723 may be formed on the interlayer insulation layer 160 and the second planar portion 724 may be formed on an inner surface of the first groove G1. The first and second planar portions 723 and 724 may be connected to each other by the connection portion 722. Accordingly, to form the common power line 272, the connection portion 722 may increase the entire line width of the

common power line 722 in the predetermined range. Thus, resistance of the common voltage may be reduced. The width of the first and second planar portions 723 and 724 may be the same as the predetermined range to form the common power line 272.

[0064] A wire having low resistance may be developed, however the low resistance wire may require material development and process development. According to an embodiment, the common power line may include the planar portion and the connection portion that increase the line width of the common power line such that the resistance of the common voltage may be reduced. Thus, a drop of the common voltage may be prevented in the common power line. Accordingly, a relatively lower voltage may be applied as the common voltage such that the power consumption may be advantageously reduced. Also, luminance deviation of the organic light emitting element may be beneficially reduced.

[0065] When providing the common voltage having the same resistance, the width of the common power line may be reduced by the connection portion, and thus the aperture ratio may be increased and the design space may be obtained.

[0066] The substrate main body may comprise a multi-layered insulating material or a single-layered insulating material. In addition, the substrate main body may be a single-layered insulating material, and another insulating material may be disposed between the substrate main body and the driving circuit.

[0067] When two insulating materials are disposed under the driving circuit, they may be referred to as a first insulating material and a second insulating material, respectively. Here, the second insulating material may be disposed on the first insulating material, and the driving circuit may be disposed on the second insulating material.

[0068] All of the elements disposed under the driving circuit may be commonly referred to as a lower structure. Similarly, all of the elements disposed on the organic light emitting element may be commonly referred to as an upper structure.

[0069] Here, the lower structure comprises a first portion and a second portion, and the second portion has a height different from that of the first portion. Further, at least one wire is continuously disposed on the first and second portions and includes at least one step.

[0070] When the first and second insulating materials are disposed under the driving circuit, the first portion of the lower structure corresponds to the first insulating material, and the second portion of the lower structure corresponds to the second insulating material.

[0071] In the above, the first insulating material may include a glass substrate.

[0072] Alternatively, the substrate main body, the interlayer insulation layer, the gate insulation layer, and the buffer layer may each be unitary structures, and may be patterned using half tone masks.

[0073] Exemplary embodiments have been disclosed herein, and although specific terms are employed, they are used and are to be interpreted in a generic and descriptive sense only and not for purpose of limitation. Accordingly, it will be understood by those of ordinary skill in the art that various changes in form and details may be made without departing from the spirit and scope of the present invention as set forth in the following claims.

What is claimed is:

1. An organic light emitting diode (OLED) display, comprising:

a substrate main body;
a driving circuit on the substrate main body;
an organic light emitting element on the driving circuit; and
a front substrate covering the organic light emitting element and coupled to the substrate main body, wherein the driving circuit includes a wire, the wire including:

a planar portion parallel to a surface of the substrate main body, and
a connection portion connected to the planar portion and extending in a direction orthogonal to the substrate main body.

2. The organic light emitting diode (OLED) display as claimed in claim 1, wherein the driving circuit includes:

a switching thin film transistor connected to a gate line and a data line, the gate line and data line intersecting each other and being insulated from each other,
a storage capacitor connected to the switching thin film transistor and a common power line, the common power line being insulated from the gate line and the data line, and
a driving thin film transistor connected to the switching thin film transistor, the storage capacitor, the common power line, and the organic light emitting element.

3. The organic light emitting diode (OLED) display as claimed in claim 2, wherein the wire comprises the common power line.

4. The organic light emitting diode (OLED) display as claimed in claim 2, further comprising an interlayer insulation layer and a gate insulator layer on the substrate main body, wherein:

the storage capacitor includes capacitor plates, the capacitor plates being insulated from one another by the interlayer insulation layer,

the driving thin film transistor includes a gate electrode, the gate electrode being insulated by the gate insulator layer in a thickness direction thereof, and

the connection portion is disposed on an inner side surface of a hole in the interlayer insulation layer and the gate insulator layer.

5. The organic light emitting diode (OLED) display as claimed in claim 4, wherein:

the interlayer insulation layer and the gate insulator layer include a plurality of holes therein, and

the common power line includes a plurality of connection portions, the plurality of connection portions being respectively disposed on inner side surfaces of the plurality of holes.

6. The organic light emitting diode (OLED) display as claimed in claim 4, wherein the planar portion includes:

a first planar portion on the interlayer insulation layer, and
a second planar portion on an inner surface of the substrate main body in the hole, the second planar portion being connected to the first planar portion by the connection portion.

7. The organic light emitting diode (OLED) display as claimed in claim 2, further comprising an interlayer insulation layer on the substrate main body, wherein:

the storage capacitor includes capacitor plates, the capacitor plates being insulated from one another by the interlayer insulation layer,

the interlayer insulation layer includes a first groove therein, and

the connection portion is disposed on an inner side surface of the at least one first groove in the interlayer insulation layer.

8. The organic light emitting diode (OLED) display as claimed in claim 7, further comprising a gate insulation layer on the substrate main body, wherein:

the driving thin film transistor includes a gate electrode, the gate electrode being insulated by the gate insulator layer in a thickness direction thereof, and

the interlayer insulation layer includes at least one first corresponding portion, the at least one first corresponding portion forming the first groove and being formed on an inner surface of a second groove in the gate insulator layer.

9. The organic light emitting diode (OLED) display as claimed in claim 8, further comprising a buffer layer on an inner surface of the substrate main body, wherein the gate insulation layer includes a second corresponding portion, the second corresponding portion forming the second groove and being formed on:

an inner surface of a third groove in the buffer layer, and
the inner surface of the substrate main body.

10. The organic light emitting diode (OLED) display as claimed in claim 9, wherein:

the interlayer insulation layer includes a plurality of the first grooves therein,

the gate insulator layer includes a plurality of the second grooves therein,

the buffer layer includes a plurality of the third grooves therein, and

the common power line includes a plurality of connection portions, the plurality of connection portions being respectively disposed on inner surfaces of the first grooves and being connected to each other through the planar portion.

11. The organic light emitting diode (OLED) display as claimed in claim 7, wherein the planar portion includes:

a first planar portion on the interlayer insulation layer, and
a second planar portion on an inner bottom surface of the first groove, the second planar portion being connected to the first planar portion by the connection portion.

12. An organic light emitting diode (OLED) display, comprising:

a lower structure including a first portion that is substantially flat and a second portion that has a different height than the first portion;

a driving circuit on the lower structure, the driving circuit having at least one wire;

an organic light emitting element on the driving circuit; and
an upper structure on the organic light emitting element, wherein the at least one wire is continuously disposed on the first and second portions and including at least one step.

13. The organic light emitting diode (OLED) display as claimed in claim 1, wherein the driving circuit includes:

a switching thin film transistor connected to a gate line and a data line, the gate line and data line intersecting each other and being insulated from each other,

a storage capacitor connected to the switching thin film transistor and a common power line, the common power line being insulated from the gate line and the data line, and

a driving thin film transistor connected to the switching thin film transistor, the storage capacitor, the common power line, and the organic light emitting element.

14. The organic light emitting diode (OLED) display as claimed in claim **13**, wherein the wire comprises the common power line.

15. The organic light emitting diode (OLED) display as claimed in claim **12**, wherein the lower structure includes:

a first insulating material; and

a second insulating material on the first insulating material.

16. The organic light emitting diode (OLED) display as claimed in claim **15**, wherein the first insulating material includes a glass substrate.

17. The organic light emitting diode (OLED) display as claimed in claim **15**, wherein the first insulating material is a unitary structure.

18. The organic light emitting diode (OLED) display as claimed in claim **15**, wherein the second insulating material is a unitary structure.

19. The organic light emitting diode (OLED) display as claimed in claim **15**, wherein the first portion corresponds to the first insulating material, and the second portion corresponds to the second insulating material.

20. The organic light emitting diode (OLED) display as claimed in claim **12**, wherein the lower structure is a unitary structure.

* * * * *

专利名称(译)	有机发光二极管显示器		
公开(公告)号	US20110227896A1	公开(公告)日	2011-09-22
申请号	US13/051753	申请日	2011-03-18
[标]申请(专利权)人(译)	HWANG杨		
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当前申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
[标]发明人	HWANG YOUNG IN		
发明人	HWANG, YOUNG-IN		
IPC分类号	G09G3/32 G06F3/038		
CPC分类号	H01L27/3279 H01L27/3276 H01L27/3258		
优先权	1020100024422 2010-03-18 KR 1020110023871 2011-03-17 KR		
其他公开文献	US9013461		
外部链接	Espacenet USPTO		

摘要(译)

一种有机发光二极管 (OLED) 显示器, 包括基板主体;基板主体上的驱动电路;驱动电路上的有机发光元件;覆盖有机发光元件并连接到基板主体的前基板, 其中驱动电路包括导线, 导线包括平行于基板主体表面的平面部分, 以及连接到平面的连接部分部分并且在垂直于基板主体的方向上延伸。

